

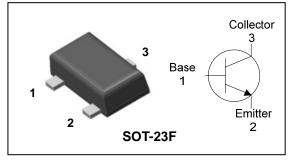
NPN Silicon Transistor

 $(Ta=25^{\circ}C)$ 

### **Features**

- High  $\beta$  & low saturation transistor.  $h_{FE}$ =400 Min. @V<sub>CE</sub>=1V, Ic=100mA
- Suitable for large current drive directly.
- Application for IRED Drive transistor in remote transmitter.

### **PIN Connection**



## **Ordering Information**

Type NO.	Marking	Package Code
STD123ASF	<u>12A</u> (1) ②	SOT-23F

① Device Code ② Year&Week Code

#### Absolute maximum ratings

10501010 maximum ramigs			(1a-25 C)
Characteristic	Symbol	Ratings	Unit
Collector-Base voltage	V <sub>CBO</sub>	10	V
Collector-Emitter voltage	V <sub>CEO</sub>	6	V
Emitter-Base voltage	V <sub>EBO</sub>	3	V
Collector current	Ι <sub>C</sub>	1	А
Collector dissipation	P <sub>C</sub> *	350	mW
Junction temperature	Tj	150	°C
Storage temperature	T <sub>stg</sub>	-55~150	°C

\* : Package mounted on 99.5% alumina 10×8×0.1mm

### **Electrical Characteristics**

Electrical Characteristics (Ta=25°C)						=25°C)
Characteristic	Symbol	<b>Test Condition</b>	Min.	Тур.	Max.	Unit
Collector-Base breakdown voltage	BV <sub>CBO</sub>	$I_{C} = 50 \mu A, I_{E} = 0$	10	-	-	V
Collector-Emitter breakdown voltage	$BV_{CEO}$	$I_{C}=1mA$ , $I_{B}=0$	6	-	-	V
Emitter-Base breakdown voltage	$BV_{EBO}$	$I_{E} = 50 \mu A, I_{C} = 0$	3	-	-	V
Collector cut-off current	I <sub>CBO</sub>	$V_{CB}$ =10V, $I_E$ =0	-	-	0.1	μΑ
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB}$ =3V, $I_{C}$ =0	-	-	0.1	μΑ
DC current gain	h <sub>FE</sub>	$V_{CE}$ =1V, $I_C$ =100mA	400	-	-	-
Collector-Emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{C}$ =500mA, $I_{B}$ =50mA	-	0.1	0.3	V
Transistor frequency	f <sub>T</sub>	$V_{CE}$ =5V, $I_{C}$ =50mA	-	260	-	MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB}$ =10V, $I_E$ =0, f=1MHz	-	5	-	pF
On resistance	R <sub>ON</sub>	f=1KHz, $I_B$ =1mA, $V_{IN}$ =0.3V	-	0.6	-	Ω

## **Electrical Characteristic Curves**

#### Fig. 1 P<sub>C</sub> - T<sub>a</sub>

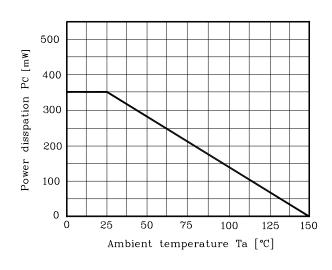
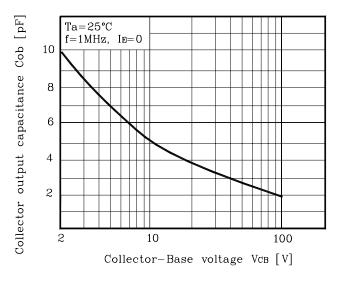


Fig. 3 C<sub>Ob</sub>-V<sub>CB</sub>





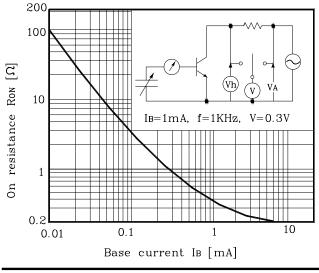


Fig. 2 V<sub>CE(sat)</sub>-I<sub>C</sub>

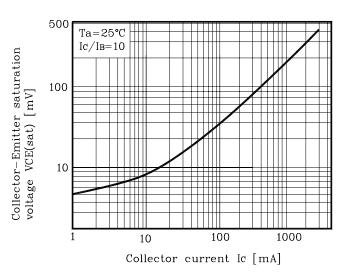
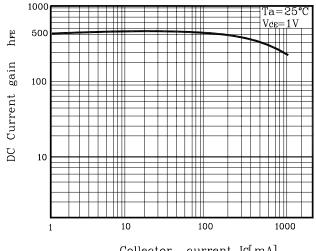
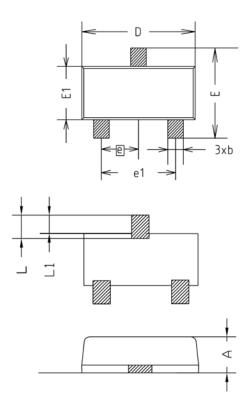


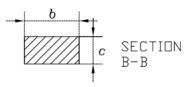
Fig. 4 h<sub>FE</sub>.I<sub>C</sub>

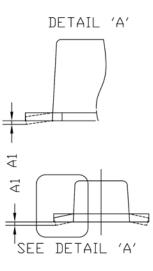


Collector current IC[mA]

## **Outline Dimension**

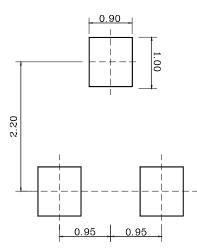






SYMBOL	MILLIMETER(mm)			NOTE
0 mbbbc	MINIMUM	NOMINAL	MAXIMUM	
A	0.80	0.90	1.00	
A1	0.00	-	0.10	
b	0.35	0.40	0.45	
С	0.10	0.15	0.20	
D	2.80	2.90	3.00	
E	2.30	2.40	2.50	
E1	1.50	1.60	1.70	
e	0.95BSC			
e1	1.80	1.90	2.00	
L	0.48	0.58	0.68	
L1	0.30	-	0.50	

#### \*Recommend PCB solder land [Unit: mm]



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